

View Online at <https://aerobasegroup.com/nsn/5961-01-058-8019>

Inclosure Material:

Metal all transistor

Overall Length:

1.653 inches all transistor

Overall Height:

0.350 inches all transistor

Overall Width:

1.050 inches all transistor

Mounting Facility Quantity:

2 all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Unthreaded hole all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

350.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

8.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Special Features:

Beta of each transistor shall be matched within 10 pct when the collector current is loaded to 2.0 amp

Terminal Type And Quantity:

1 case all transistor and 2 pin all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A110a0